TOSHIBA Transistor Silicon PNP Diffused Type (PCT process)

# 2SB906

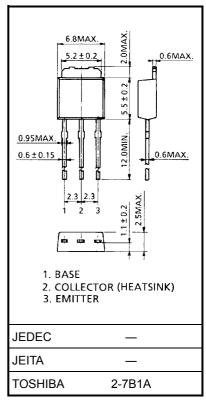
### Audio Frequency Power Amplifier Application

Unit: mm

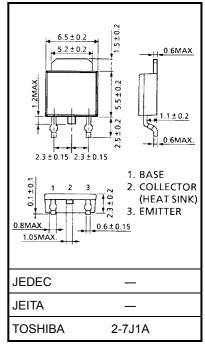
- Low collector saturation voltage
  - :  $V_{CE (sat)} = -1.0 \text{ V (typ.)} (I_{C} = -3 \text{ A}, I_{B} = -0.3 \text{ A})$
- High power dissipation:  $PC = 20 \text{ W} \text{ (Tc} = 25^{\circ}\text{C)}$
- Complementary to 2SD1221
- ハイブリッド対応外形の (B) 2SB906 (LB) もあります。

### **Maximum Ratings (Ta = 25°C)**

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		$V_{CBO}$	-60	٧	
Collector-emitter voltage		V <sub>CEO</sub>	-60	V	
Emitter-base voltage		V <sub>EBO</sub>	-7	V	
Collector current		I <sub>C</sub>	-3	Α	
Base current		Ι <sub>Β</sub>	-0.5	Α	
Collector power dissipation	Ta = 25°C	Pc	1.0	W	
	Tc = 25°C	T FC	20		
Junction temperature		Tj	150	°C	
Storage temperature range		T <sub>stg</sub>	-55 to 150	°C	



Weight: 0.36 g (typ.)



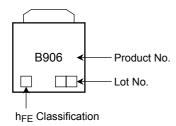
Weight: 0.36 g (typ.)

## Electrical Characteristics (Ta = 25°C)

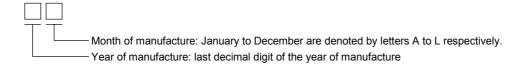
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current		I <sub>CBO</sub>	V <sub>CB</sub> = -60 V, I <sub>E</sub> = 0	_	_	-100	μΑ
Emitter cut-off current		I <sub>EBO</sub>	V <sub>EB</sub> = -7 V, I <sub>C</sub> = 0	1	_	-100	μΑ
Collector-emitter breakdown voltage		V (BR) CEO	$I_C = -50 \text{ mA}, I_B = 0$	-60	_	_	V
DC current gain		h <sub>FE (1)</sub> (Note)	V <sub>CE</sub> = -5 V, I <sub>C</sub> = -0.5 A	60	_	200	
		h <sub>FE (2)</sub>	V <sub>CE</sub> = -5 V, I <sub>C</sub> = -3 A	20	_	_	
Collector-emitter saturation voltage		V <sub>CE</sub> (sat)	I <sub>C</sub> = -3 A, I <sub>B</sub> = -0.3 A	_	-1.0	-1.7	V
Base-emitter voltage		V <sub>BE</sub>	V <sub>CE</sub> = -5 V, I <sub>C</sub> = -0.5 A	_	-1.0	-1.5	V
Transition frequency		f <sub>T</sub>	V <sub>CE</sub> = -5 V, I <sub>C</sub> = -0.5 A	_	9	_	MHz
Collector output capacitance		C <sub>ob</sub>	V <sub>CB</sub> = -10 V, I <sub>E</sub> = 0, f = 1 MHz	-	90	_	pF
Switching time	Turn-on time	t <sub>on</sub>	20 μs INPUT HB1 OUTPUT   B1    B2    B2    C2    C3    C4    C4	_	0.4	_	
	Storage time	t <sub>stg</sub>		_	1.7	_	μs
	Fall time	t <sub>f</sub>			0.5	_	

Note:  $h_{FE\ (1)}$  classification O: 60 to 120, Y: 100 to 200

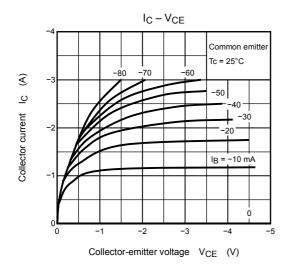
### Marking

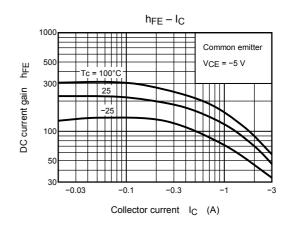


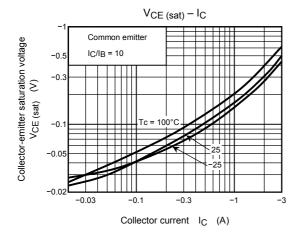
### **Explanation of Lot No.**

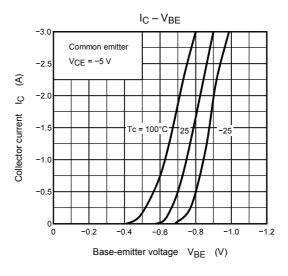


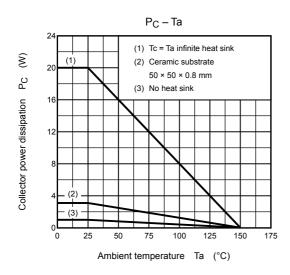
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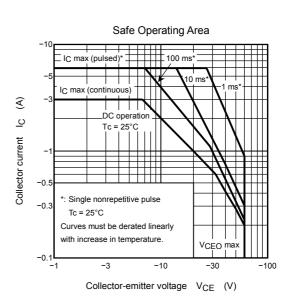












3

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